

# isc N-Channel MOSFET Transistor

# 2SK3694-01L

## **FEATURES**

- Drain Current : I<sub>D</sub>= 17A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 450V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.38 \Omega (Max) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **DESCRIPTION**

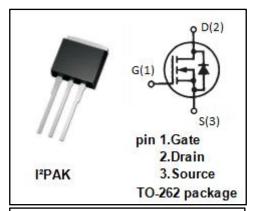
 motor drive, DC-DC converter, power switch and solenoid drive.

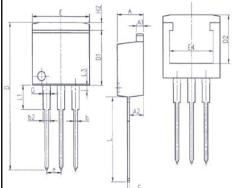
## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	450	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	17	А
I <sub>DM</sub>	Drain Current-Single Pluse	68	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	225	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.556	°C/W





	MM	
DIM	MIN	MAX
Α	4. 37	4. 77
A1	1. 22	1.42
A2	2.47	2.87
b	0.7	0.97
b2	1.17	1.42
С	0.28	0.53
D	23. 2	24.02
D1	8. 38	8.9
D2	6	1
E	9.9	10.39
E4	7.3	1
E	2. 54BSC	
G	1. 25	1.5
H2	1	1. 31
L	13.34	14.1
L1	3. 3	4.06
L3	0.95	1.15

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### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	450		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 0.25mA	3.0	5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 8.5A		0.38	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±0.1	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 450V; V <sub>GS</sub> = 0		25	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 17A; V <sub>GS</sub> = 0	-	1.8	V



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